

NPN Silicon Planar High Voltage Transistor

TO-92



Pin Definition:

1. Emitter
2. Collector
3. Base

SOT-223



Pin Definition:

1. Base
2. Collector
3. Emitter

PRODUCT SUMMARY

BV_{CBO}	600V
BV_{CEO}	400V
I_C	300mA
V_{CE(SAT)}	0.5V @ I _C / I _B = 50mA / 5mA

Features

- High BV_{ceo}, BV_{cbo}
- High current gain

Structure

- Epitaxial Planar Type

Ordering Information

Part No.	Package	Packing
TSC966CT B0G	TO-92	1,000pcs / Bulk
TSC966CT A3G	TO-92	2,000pcs / Ammo
TSC966CW R0G	SOT-223	2,500pcs / 13" Reel

Note: "G" denote for Halogen Free Product

Absolute Maximum Rating (T_A=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V _{CBO}	600	V
Collector-Emitter Voltage	V _{CES}	600	V
Collector-Emitter Voltage	V _{CEO}	400	V
Emitter-Base Voltage	V _{EBO}	7	V
Collector Current	DC	0.3	A
	Pulse	1	
Total Power Dissipation @ T _A =25°C	TO-92	0.9	W
	SOT-223	1	
Operating Junction Temperature	T _J	+150	°C
Operating Junction and Storage Temperature Range	T _{STG}	- 55 to +150	°C

Electrical Specifications (T_a = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage	I _C = 50uA	BV _{CBO}	600	--	--	V
Collector-Emitter Saturation Voltage	I _C = 100uA, V _{BE} = 0	BV _{CES}	600	--	--	V
Collector-Emitter Breakdown Voltage	I _C = 1mA	BV _{CEO}	400	--	--	V
Emitter-Base Breakdown Voltage	I _E = 50uA	BV _{EBO}	7	--	--	V
Collector-Base Cutoff Current	V _{CB} = 600V	I _{CBO}	--	--	0.5	uA
Collector-Emitter Cutoff Current	V _{CE} = 400V	I _{CEO}	--	--	1	uA
Emitter-Base Cutoff Current	V _{EB} = 7V	I _{EBO}	--	--	1.5	uA
Collector-Emitter Saturation Voltage	I _C = 50mA, I _B = 5mA	V _{CE(SAT)}	--	--	0.5	V
Base-Emitter Saturation Voltage	I _C = 50mA, I _B = 5mA	V _{BE(SAT)}	--	--	1	V
DC Current Transfer Ratio	V _{CE} = 5V, I _C = 1mA	h _{FE} 1	100	--	--	
	V _{CE} = 5V, I _C = 20mA	h _{FE} 2	90	--	300	
Transition Frequency	V _{CE} = 10V, I _E = 20mA	f _T	50	--	--	MHz
Output Capacitance	V _{CB} = 20V, f = 1MHz	Cob	--	--	7	pF

Electrical Characteristics Curve ($T_a = 25^\circ\text{C}$, unless otherwise noted)

Figure 1. Static Characteristics

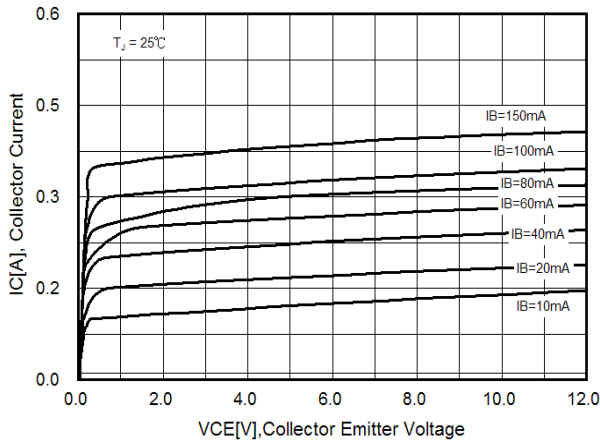


Figure 2. DC Current Gain

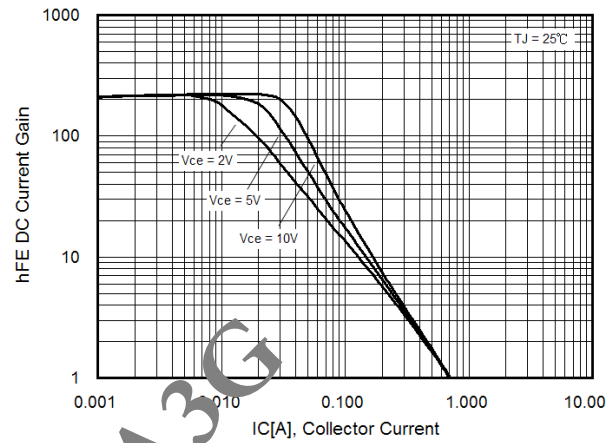


Figure 3. VCE(SAT) v.s. IC

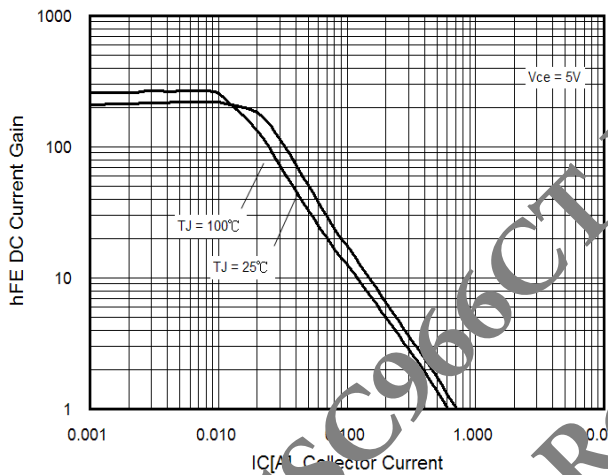


Figure 4. VBE(sat) vs IC

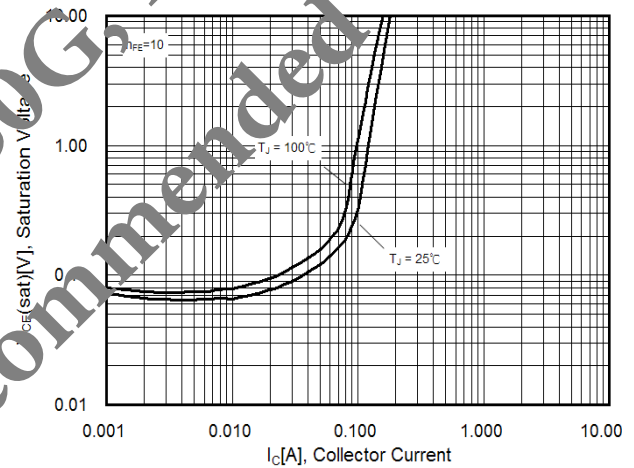


Figure 5. VBE(on) vs IC

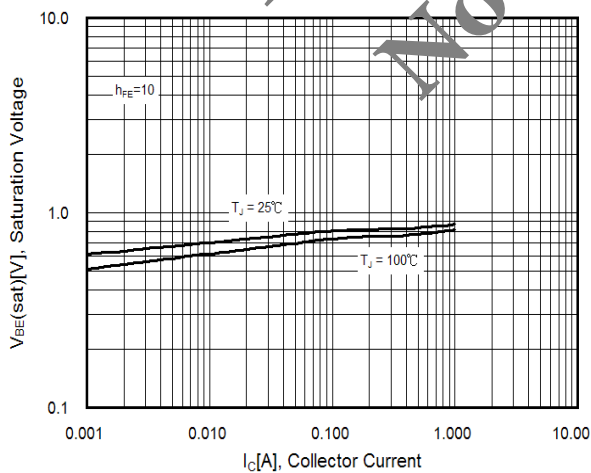
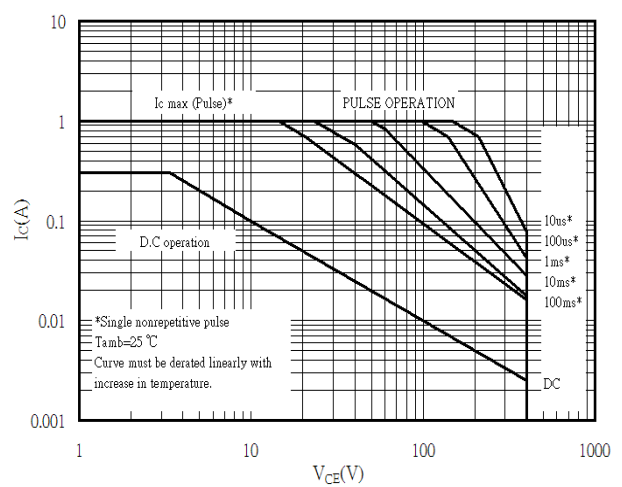
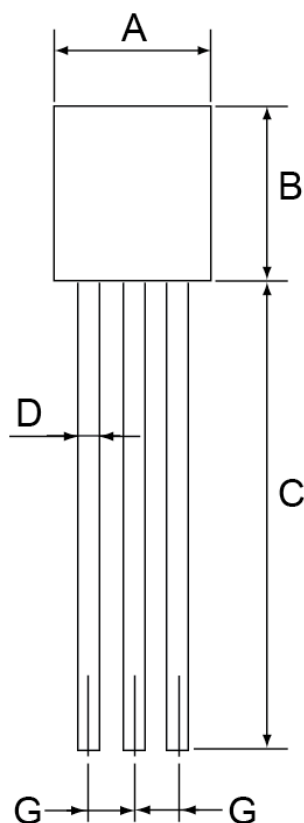


Figure 6. Safety Operation Area



TO-92 Mechanical Drawing



TO-92 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.30	4.70	0.169	0.185
B	4.30	4.70	0.169	0.185
C	14.30(typ)		0.563(typ)	
D	0.43	0.49	0.017	0.019
E	1.18	1.28	0.046	0.050
F	3.30	3.70	0.130	0.146
G	1.27	1.31	0.05	0.051
H	0.37	0.43	0.015	0.017

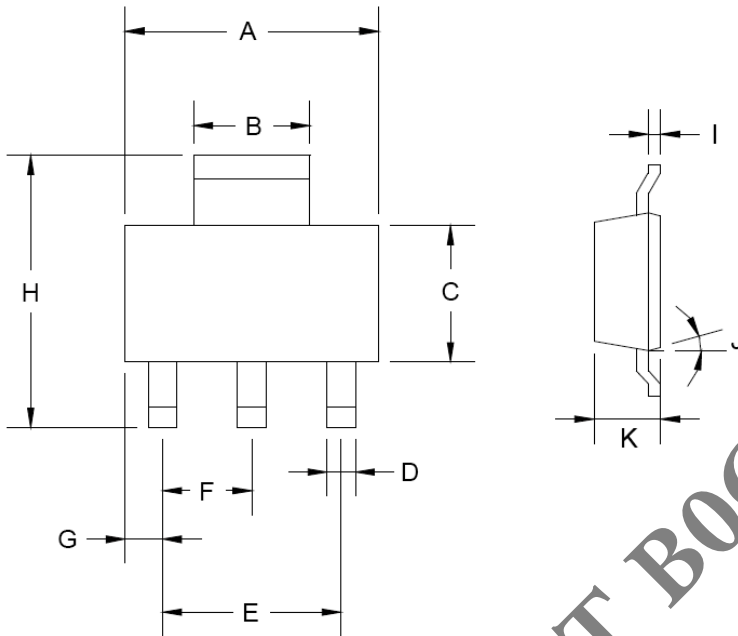
Marking Diagram



#1

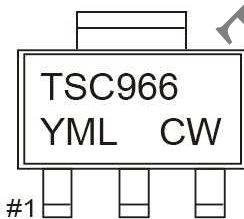
Y = Year Code
M = Month Code for Halogen Free Product
O =Jan P =Feb Q =Mar R =Apr
S =May T =Jun U =Jul V =Aug
W =Sep X =Oct Y =Nov Z =Dec
L = Lot Code

SOT-223 Mechanical Drawing



SOT-223 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	6.350	6.850	0.250	0.270
B	2.900	3.100	0.114	0.122
C	3.450	3.750	0.136	0.148
D	0.595	0.635	0.023	0.025
E	4.550	4.650	0.179	0.183
F	2.250	2.350	0.088	0.093
G	0.635	1.035	0.032	0.041
H	6.700	7.300	0.263	0.287
I	0.250	0.355	0.010	0.014
J	10°	16°	10°	16°
K	1.550	1.800	0.061	0.071

Marking Diagram



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TSC966CT B0G, A3G
Not Recommended

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